

High Voltage Transistors

PNP Silicon

BSP16T1G

Features

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	-300	Vdc
Collector-Base Voltage	V _{CBO}	-350	Vdc
Emitter-Base Voltage	V _{EBO}	-6.0	Vdc
Collector Current	Ic	-100	mAdc
Total Device Dissipation @ T _A = 25°C (Note 1)	P _D	1.5	W
Storage Temperature Range	P _D	−65 to +150	°C
Junction Temperature	TJ	150	°C

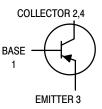
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	83.3	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Device mounted on a glass epoxy printed circuit board 1.575 in x 1.575 in x 0.059 in; mounting pad for the collector lead min. 0.93 sq. in.

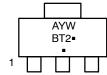
PNP SILICON HIGH VOLTAGE TRANSISTOR SURFACE MOUNT







SOT-223 CASE 318E STYLE 1



A = Assembly Location

Y = Year W = Work Week BT2 =Device Code ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
BSP16T1G	SOT-223 (Pb-Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BSP16T1G

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (I _C = –50 mAdc, I _B = 0, L = 25 mH)	V _(BR) CEO	-300	-	Vdc
Collector – Base Breakdown Voltage ($I_C = -100 \mu Adc, I_E = 0$)	V _(BR) CBO	-300	-	Vdc
Collector-Emitter Cutoff Current (V _{CE} = -250 Vdc, I _B = 0)	I _{CES}	-	-50	μAdc
Collector-Base Cutoff Current (V _{CB} = -280 Vdc, I _E = 0)	I _{CBO}	-	-1.0	μAdc
Emitter–Base Cutoff Current $(V_{EB} = -6.0 \text{ Vdc}, I_C = 0)$	I _{EBO}	_	-20	μAdo
ON CHARACTERISTICS			-	•
DC Current Gain (V _{CE} = -10 Vdc, I _C = -50 mAdc)	h _{FE}	30	120	-
Collector-Emitter Saturation Voltage (I _C = -50 mAdc, I _B = -5.0 mAdc)	V _{CE(sat)}	-	-2.0	Vdc
DYNAMIC CHARACTERISTICS				
Current Gain – Bandwidth Product (V _{CE} = -10 Vdc, I _C = -10 mAdc, f = 30 MHz)	f _T	15	-	MHz
Collector–Base Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	15	pF

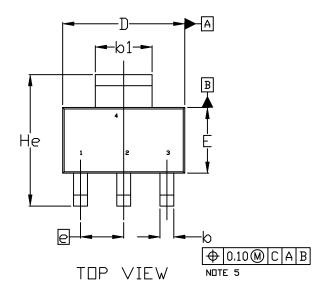
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

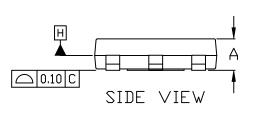


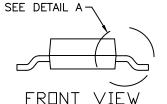


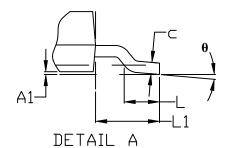
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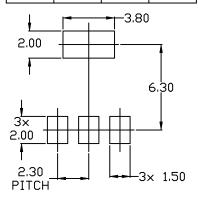




NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
 MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- 5. AI IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
- 6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS 6 AND 61.

	MILLIMETERS		
DIM	MIN.	N□M.	MAX.
Α	1.50	1.63	1.75
A1	0.02	0.06	0.10
Ø	0.60	0.75	0.89
b1	2.90	3.06	3.20
U	0.24	0.29	0.35
D	6.30	6.50	6.70
E	3.30	3.50	3.70
е	2.30 BSC		
L	0.20		
L1	1.50	1.75	2.00
He	6.70	7.00	7.30
θ	0°		10°



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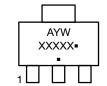
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DATE 02 OCT 2018

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: PIN 1. SOURCE 2. DRAIN 3. GATE 4. DRAIN	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	STYLE 9: PIN 1. INPUT 2. GROUND 3. LOGIC 4. GROUND	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	STYLE 12: PIN 1. INPUT 2. OUTPUT 3. NC 4. OUTPUT	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

GENERIC MARKING DIAGRAM*



A = Assembly Location

Y = Year W = Work Week

XXXXX = Specific Device Code

= Pb-Free Package

(Note: Microdot may be in either location)
*This information is generic. Please refer to
device data sheet for actual part marking.
Pb-Free indicator, "G" or microdot "•", may
or may not be present. Some products may

not follow the Generic Marking.

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